

OKI electronic components

KGF1521

Small-Signal Amplifier for UHF-Band and PCS Frequencies

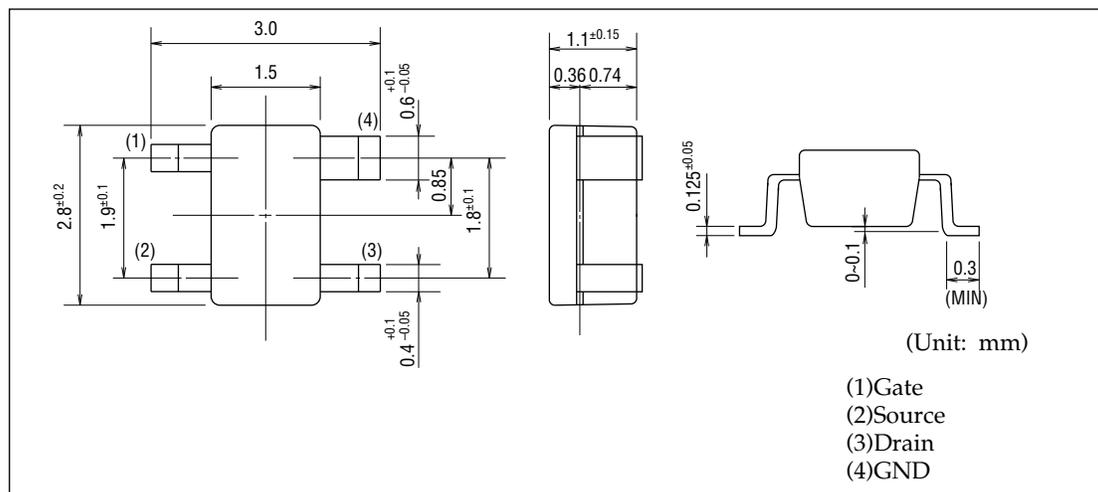
GENERAL DESCRIPTION

The KGF1521 is a high-performance GaAs FET small-signal amplifier for L band frequencies that features low-voltage operation, low-current dissipation, low noise, and low distortion. The KGF1521 specifications are guaranteed by the fixed matching circuit of 3 V and 1.9 GHz, although external impedance matching circuits are required. Because of its high 3rd-order intercept point even at the low-operating current, the KGF1521 is ideal as a small-signal amplifier for L-band personal handy phones, such as digital keying cordless phones that require low intermodulation properties.

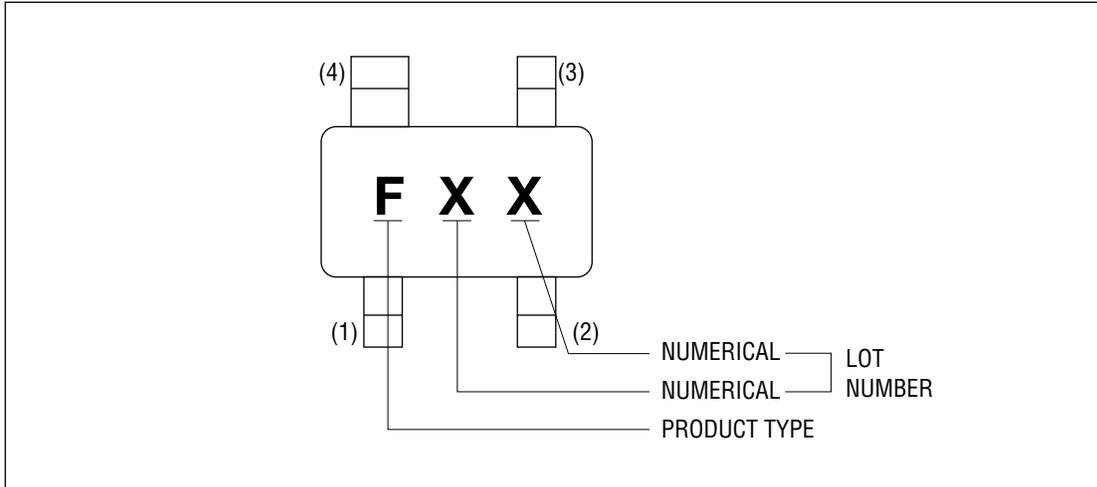
FEATURES

- Low voltage and low current operation: 3 V, 2.5 mA (max)
- Specifications guaranteed by the fixed matching circuits at 3 V, 1.9 GHz
- Low noise figure: 1.8 dB (typ) at 1.9 GHz
- High linear gain: 12.5 dB (typ) at 1.9 GHz
- High output power: 1 dB compression point = 0 dBm (typ) at 1.9 GHz
- Low distortion: 3rd-order intercept point = 12 dBm (typ) at 1.9 GHz
- Self-bias circuit configuration with built-in source capacitor
- Surface mount 4-pin SOP plastic package

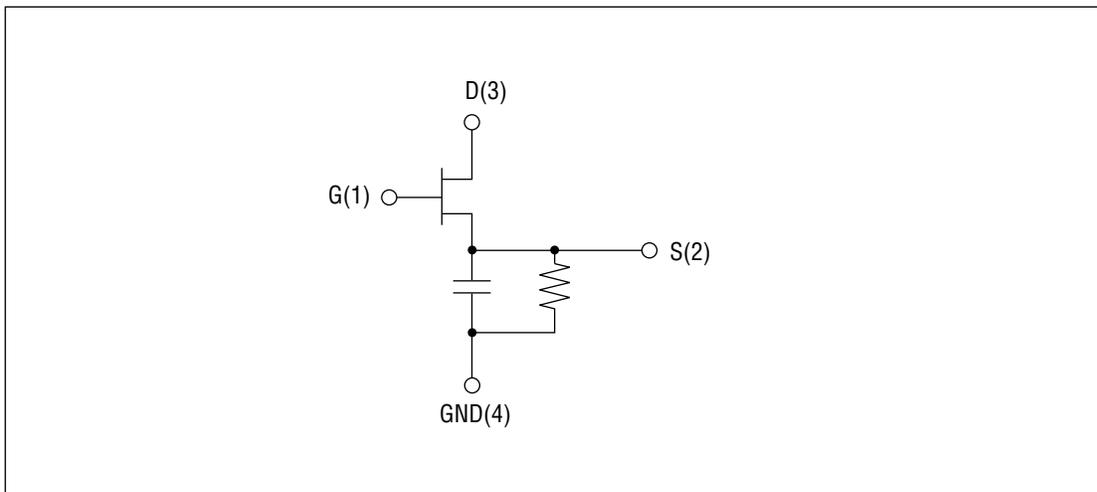
PACKAGE OUTLINE



MARKING



CIRCUIT



ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Condition	Unit	Min.	Max.
Drain-source voltage	V_{DS}	$T_a = 25^\circ\text{C}$	V	—	4.0
Gate-source voltage	V_{GS}	$T_a = 25^\circ\text{C}$	V	-3.0	0.4
Drain current	I_{DS}	$T_a = 25^\circ\text{C}$	mA	—	50
Total power dissipation	P_{tot}	$T_a = 25^\circ\text{C}$	mW	—	200
Channel temperature	T_{ch}	—	$^\circ\text{C}$	—	150
Storage temperature	T_{stg}	—	$^\circ\text{C}$	-45	125

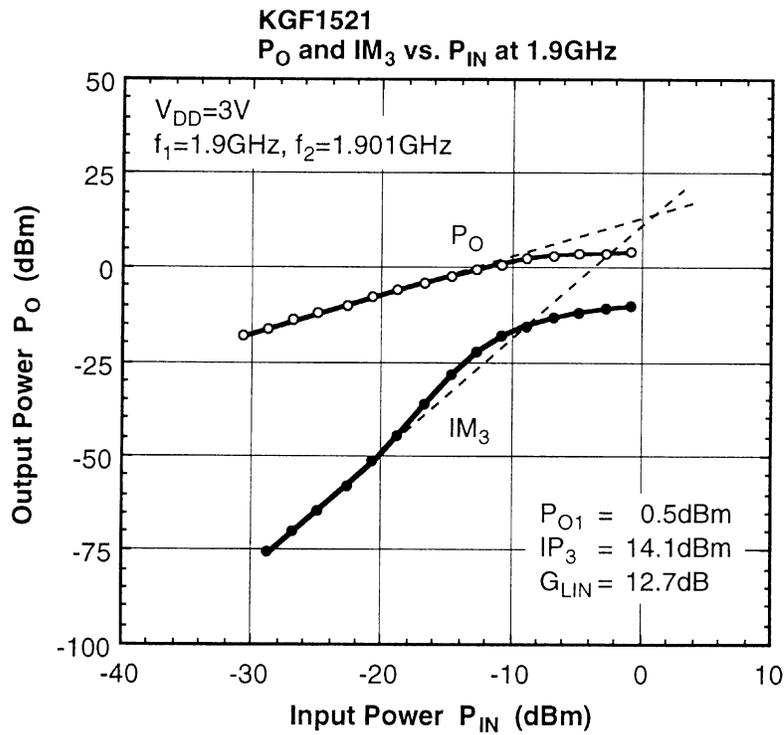
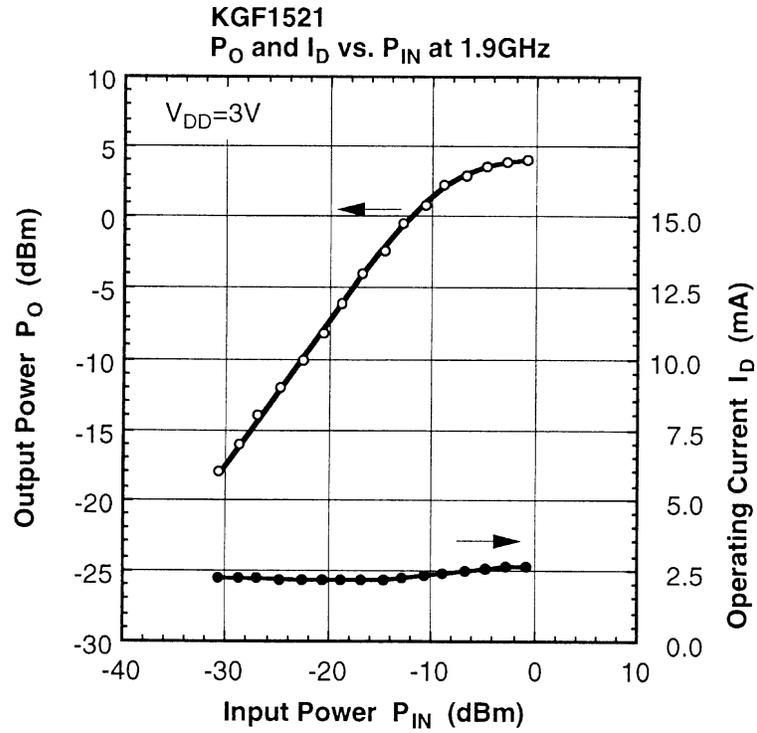
ELECTRICAL CHARACTERISTICS

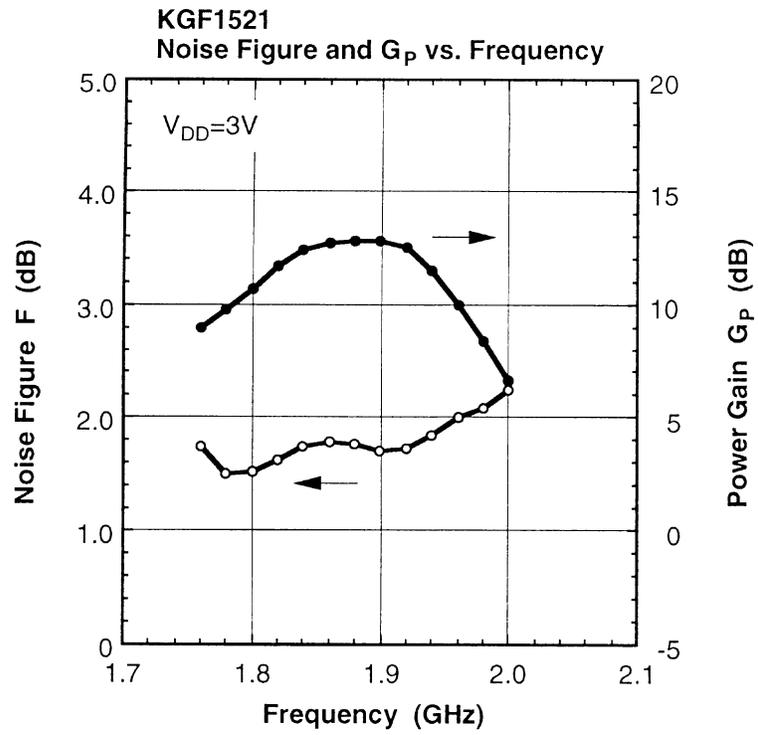
(Ta = 25°C)

Item	Symbol	Condition	Unit	Min.	Typ.	Max.
Gate-source leakage current	I_{GSS}	$V_{GS} = -3\text{ V}$	μA	—	—	30
Gate-drain leakage current	I_{GDO}	$V_{GD} = -6\text{ V}$	μA	—	—	30
Drain-source leakage current	$I_{DS(off)}$	$V_{DS} = 3\text{ V}, V_{GS} = -2\text{ V}$	μA	—	—	30
Drain current	I_{DSS}	$V_{DS} = 3\text{ V}, V_{GS} = 0\text{ V}$	mA	15	25	—
Operating current	I_D	(*1), $P_{IN} = -20\text{ dBm}$	mA	—	2.0	2.5
Gate-source cut-off voltage	$V_{GS(off)}$	$V_{DS} = 3\text{ V}, I_{DS} = 100\ \mu\text{A}$	V	-1.4	—	-0.6
Transconductance	g_m	$V_{DS} = 3\text{ V}, I_{DS} = 2\text{ mA}$	mS	14	17	—
Noise figure	F	(*1)	dB	—	1.8	2.5
Linear gain	G_{LIN}	(*1), $P_{IN} = -20\text{ dBm}$	dB	11.0	12.5	—
Output power	P_{O1}	(*1)	dBm	-3.0	0	—
Third-order intercept point	IP_3	(*2), $f_2 = 1.901\text{ GHz}$	dBm	—	12	—

*1 Self-bias condition: $V_{DD} = 3\text{ V} \pm 0.3\text{ V}$, $V_G = 0\text{ V}$, $f = 1.9\text{ GHz}$

RF CHARACTERISTICS



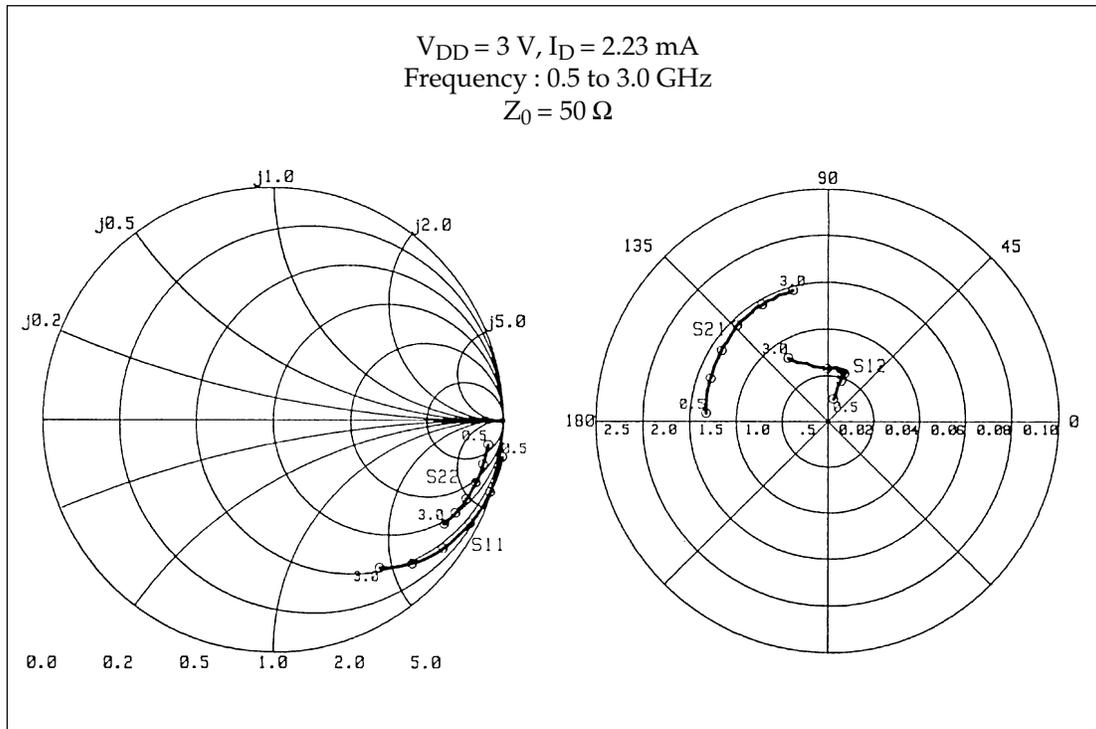


Typical S-Parameters

 $V_{DD} = 3\text{ V}$, $I_D = 2.23\text{ mA}$

Freq(MHz)	MAG(S ₁₁)	ANG(S ₁₁)	MAG(S ₂₁)	ANG(S ₂₁)	MAG(S ₁₂)	ANG(S ₁₂)	MAG(S ₂₂)	ANG(S ₂₂)
500.0	1.006	-9.13	1.330	176.30	0.010	77.66	0.939	-6.40
600.0	1.004	-10.96	1.338	172.44	0.012	75.14	0.937	-7.42
700.0	1.001	-12.83	1.346	168.98	0.013	74.67	0.934	-8.59
800.0	0.998	-14.68	1.353	165.93	0.015	74.75	0.933	-9.60
900.0	0.995	-16.53	1.354	163.08	0.016	74.68	0.932	-10.71
1000.0	0.992	-18.33	1.359	160.07	0.018	72.86	0.930	-11.75
1100.0	0.987	-20.18	1.359	157.16	0.018	73.49	0.927	-12.88
1200.0	0.983	-22.02	1.369	154.84	0.020	72.57	0.926	-13.89
1300.0	0.978	-23.88	1.374	152.28	0.021	71.18	0.925	-14.99
1400.0	0.972	-25.70	1.376	149.79	0.022	70.96	0.922	-16.04
1500.0	0.966	-27.62	1.388	146.67	0.022	71.48	0.920	-17.08
1600.0	0.959	-29.46	1.397	144.51	0.022	70.80	0.918	-18.12
1700.0	0.950	-31.22	1.393	141.98	0.023	70.04	0.914	-18.95
1800.0	0.941	-33.22	1.409	138.88	0.023	71.52	0.911	-20.20
1900.0	0.935	-35.13	1.418	136.15	0.023	72.15	0.910	-21.19
2000.0	0.924	-37.04	1.434	133.84	0.022	75.12	0.905	-22.16
2100.0	0.915	-38.95	1.440	131.23	0.023	80.13	0.903	-23.29
2200.0	0.905	-40.60	1.435	128.21	0.024	80.50	0.900	-24.24
2300.0	0.893	-42.34	1.440	125.19	0.023	82.84	0.894	-25.15
2400.0	0.881	-44.23	1.458	122.85	0.023	87.86	0.892	-26.13
2500.0	0.866	-45.91	1.448	120.01	0.023	91.51	0.887	-26.95
2600.0	0.852	-47.73	1.455	116.96	0.024	97.20	0.883	-27.96
2700.0	0.837	-49.40	1.447	114.13	0.025	105.76	0.879	-28.80
2800.0	0.821	-51.16	1.467	111.27	0.027	110.78	0.874	-29.63
2900.0	0.806	-52.74	1.454	108.42	0.029	118.12	0.871	-30.58
3000.0	0.790	-54.25	1.462	105.45	0.032	122.68	0.868	-31.21

Typical S-Parameters



Test Circuit and Bias Configuration for KGF1521 at 1.9 GHz

